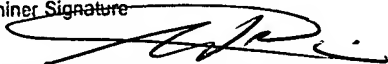


Substitute Form PTO-1449 (Modified)  <b>Information Disclosure Statement by Applicant</b> (Use several sheets if necessary)  (37 CFR §1.98(b))	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. <b>14925-010001</b>	Application No. <b>Unknown</b>
	Applicant <b>Takao Nakamura et al.</b>		
	Filing Date <b>March 23, 2004</b>	Group Art Unit <b>Unknown</b>	

U.S. Patent Documents							
Examiner Initial	Desig. ID	Document Number	Issue Date	Patentee	Class	Subclass	Filing Date If Appropriate
<i>WSL</i>	AA	5,396,103	03/07/1995	Oiu et al.			
<i>WSL</i>	AB	5,548,137	08/20/1996	Fan et al.			
	AC						
	AD						
	AE						

Foreign Patent Documents or Published Foreign Patent Applications								
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
<i>WSL</i>	AF	06-310815	11/04/1994	Japan			X (Abstract Only)	
<i>WSL</i>	AG	06-005920	01/14/1994	Japan			X (Abstract Only)	
	AH							

Other Documents (include Author, Title, Date, and Place of Publication)		
Examiner Initial	Desig. ID	Document
<i>WSL</i>	AI	Takao Nakamura et al., Optronics (2000) No. 12, pp.126-131 (partial translation)
<i>WSL</i>	AJ	Y. Fan et al., "Graded band gap ohmic contact to p-ZnSe", <u>Appl. Phys. Lett.</u> , 61 (26), 12/28/1992, pp. 3160-3162
	AK	

Examiner Signature 	Date Considered <b>6/8/05</b>
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	